FAIRCHILD

SEMICONDUCTOR

2N6518

High Voltage Transistor

- Collector-Emitter Voltage: V_{CEO}= -250V
 Collector Dissipation: P_C (max)=625mW
 Complement to 2N6515

PNP Epitaxial Silicon Transistor



1. Emitter 2. Base 3. Collector

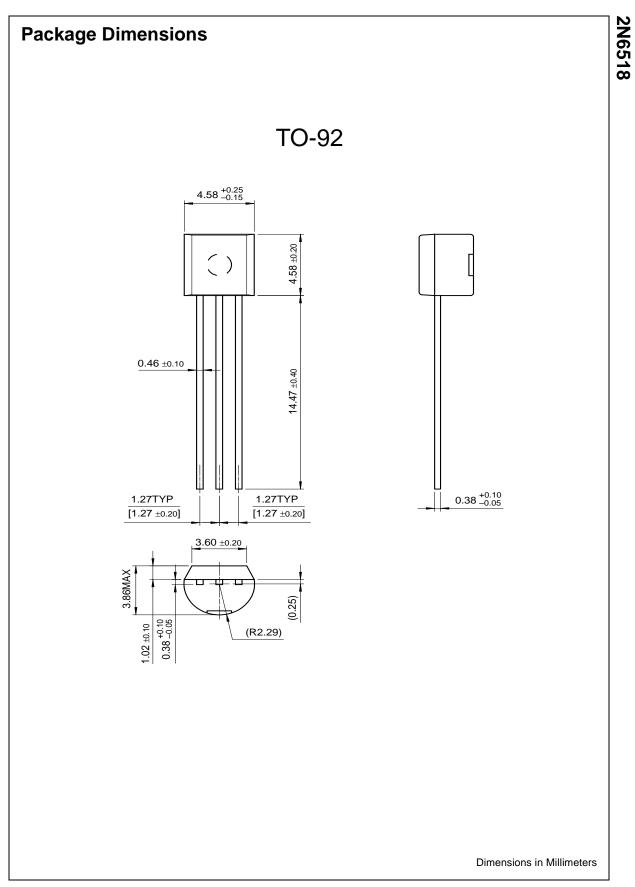
14

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	-250	V
V _{CEO}	Collector-Emitter Voltage	-250	V
V _{EBO}	Emitter-Base Voltage	-5	V
c	Collector Current	-500	mA
в	Base Current	-250	mA
P _C	Collector Power Dissipation	625	mW
	Derate above 25°C	5	mW/°C
ТJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV _{CBO}	* Collector-Base Breakdown Voltage	I _C = -100μA, I _E =0	-250		V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -1mA, I _B =0	-250		V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = -10μA, I _C =0	-5		V
I _{CBO}	Collector Cut-off Current	V _{CB} = -150V, I _E =0		-50	nA
I _{EBO}	Emitter Cut-off Current	V _{EB} = -4V, I _C =0		-50	nA
h _{FE}	* DC Current Gain	V _{CE} = -10V, I _C = -1mA V _{CE} = -10V, I _C = -10mA V _{CE} = -10V, I _C = -30mA V _{CE} = -10V, I _C = -50mA V _{CE} = -10V, I _C = -100mA	35 50 50 45 25	300 220	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I_{C} = -10mA, I_{B} = -1mA I_{C} = -20mA, I_{B} = -2mA I_{C} = -30mA, I_{B} = -3mA I_{C} = -50mA, I_{B} = -5mA		-0.30 -0.35 -0.50 -1	V V V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I_{C} = -10mA, I_{B} = -1mA I_{C} = -20mA, I_{B} = -2mA I_{C} = -30mA, I_{B} = -3mA		-0.75 -0.85 -0.90	V V V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = -10V, I _C = -100mA		-2	V
fT	* Current Gain Bandwidth Product	V _{CE} = -20V, I _C = -10mA, f=20MHz	40	200	MHz
C _{ob}	Output Capacitance	V _{CB} = -20V, I _E =0, f=1MHz		6	pF
C _{EB}	Emitter-Base Capacitance	V _{EB} = -0.5V, I _C =0, f=1MHz		100	pF
ON	Turn On Time	V _{BE} (off)= -2V, V _{CC} = -100V I _C = -50mA, I _{B1} = -10mA		200	ns
OFF	Turn Off Time	V _{CC} = -100V, I _C = -50mA I _{B1} =I _{B2} =10mA		3.5	ns



TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.